2SB0745, 2SB0745A (2SB745, 2SB745A)

Silicon PNP epitaxial planar type

For low-frequency and low-noise amplification Complementary to 2SD0661 (2SD661) and 2SD0661A (2SD661A)

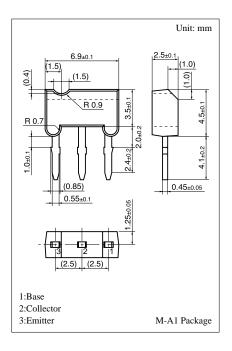
Features

Transistors

- Low noise voltage NV.
- High foward current transfer ratio h_{FE}.
- M type package allowing easy automatic and manual insertion as well as stand-alone fixing to the printed circuit board.

Absolute Maximum Ratings (Ta=25°C)

Parameter		Symbol	Ratings	Unit	
Collector to	2SB0745	17	-35	***	
base voltage	2SB0745A	V_{CBO}	-55	V	
Collector to	2SB0745	37	-35		
emitter voltage	2SB0745A	V_{CEO}	-55	V	
Emitter to base voltage		V_{EBO}	-5	V	
Peak collector current		I_{CP}	-200	mA	
Collector current		I_C	-50	mA	
Collector power dissipation		P_{C}	400	mW	
Junction temperature		T_{j}	150	°C	
Storage temperature		T_{stg}	−55 ~ +150	°C	



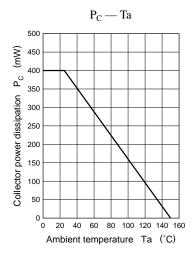
Electrical Characteristics (Ta=25°C)

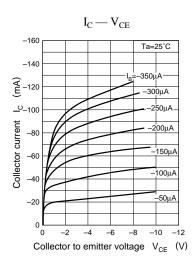
Paramete	er	Symbol Conditions min typ		typ	max	Unit	
Collector cutoff current		I _{CBO}	$V_{CB} = -10V, I_{E} = 0$			-100	nA
		I _{CEO}	$V_{CE} = -10V, I_{B} = 0$			-1	μА
Collector to base	2SB0745	37	I 10::A I 0	-35			V
voltage	2SB0745A	V _{CBO}	$I_{\rm C} = -10 \mu A, I_{\rm E} = 0$	-55			
Collector to emitter	2SB0745	**	$I_{\rm C} = -2mA, I_{\rm B} = 0$	-35			V
voltage	2SB0745A	V _{CEO}		-55			
Emitter to base voltage		V _{EBO}	$I_{\rm E} = -10 \mu A, I_{\rm C} = 0$	-5			V
Forward current transfer ratio		h _{FE} *	$V_{CB} = -5V$, $I_E = 2mA$	180		700	
Collector to emitter saturation voltage V		V _{CE(sat)}	$I_C = -100 \text{mA}, I_B = -10 \text{mA}$			- 0.6	V
Base to emitter voltage V		V _{BE}	$V_{CE} = -1V, I_{C} = -100mA$		- 0.7	-1	V
Transition frequency f _T		f_{T}	$V_{CB} = -5V, I_E = 2mA, f = 200MHz$		150		MHz
Noise voltage		NV	$V_{CE} = -10V$, $I_{C} = -1$ mA, $G_{V} = 80$ dB $R_{v} = 100$ k Ω , Function = FLAT			150	mV

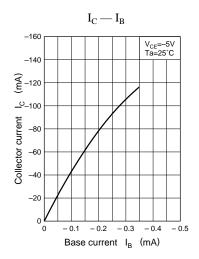
*hFE Rank classification

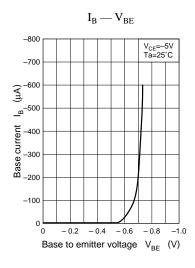
Rank	R	S	T	
h_{FE}	180 ~ 360	260 ~ 520	360 ~ 700	

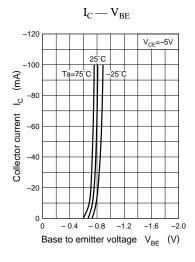
Note.) The Part numbers in the Parenthesis show conventional part number.

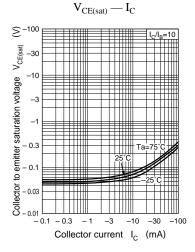


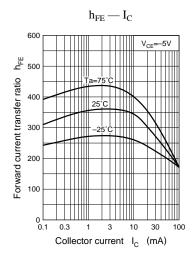


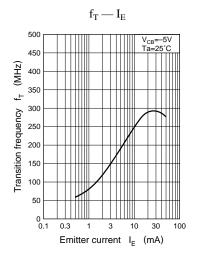


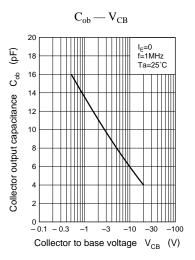


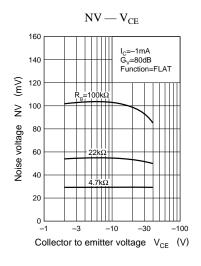


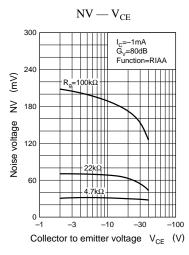


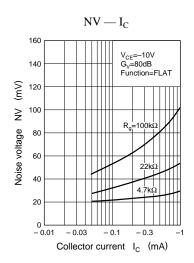


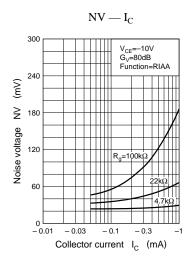


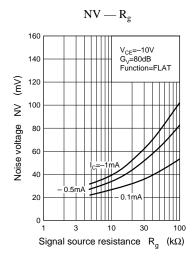


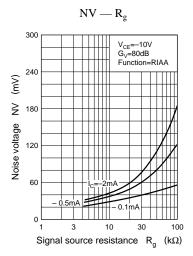












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